BT139 series E

GENERAL DESCRIPTION

Glass passivated, sensitive gate triacs in a plastic envelope, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

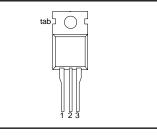
QUICK REFERENCE DATA

PIN CONFIGURATION

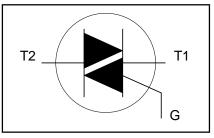
SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BT139- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	500E 500 16 140	600E 600 16 140	800E 800 16 140	V A A

PINNING - TO220AB

PIN	PIN DESCRIPTION		
1	main terminal 1		
2	main terminal 2		
3	gate		
tab	main terminal 2		



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{drm}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	-800 800	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 99$ °C full sine wave; $T_j = 25$ °C prior to surge	-		16		A
		t = 20 ms	-		140		A
124	1 ² t for fusing	t = 16.7 ms	-		150		A A ² s
l²t dI _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after	t = 10 ms I _{TM} = 20 A; I _G = 0.2 A; dI _G /dt = 0.2 A/μs	-		98		A-S
	triggering	T2+G+	-		50		A/μs
		T2+ G-	-		50		A/µs
		T2- G- T2- G+			50 10		A/μs A/μs
I _{GM} V _{GM} P _{GM}	Peak gate current Peak gate voltage Peak gate power		-		2 5 5		A V W
$\begin{array}{c} P_{G(AV)}\\ P_{G(AV)}\\ T_{stg}\\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125		ůů Å

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

BT139 series E

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air	-	- - 60	1.2 1.7 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

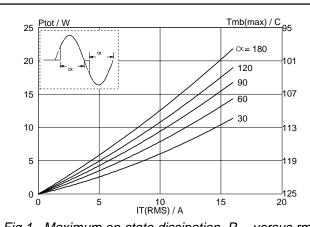
SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	-	2.5	10	mA
			T2+ G-	-	4.0	10	mA
			T2- G-	-	5.0	10	mA
			T2- G+	-	11	25	mA
I,	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
-			T2+ G+	-	3.2	30	mA
			T2+ G-	-	16	40	mA
			T2- G-	-	4.0	30	mA
			T2- G+	-	5.5	40	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	4.0	30	mA
I _H V _T V _{GT}	On-state voltage	$I_{T} = 20 \text{ A}$		-	1.2	1.6	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
.		$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125 ^{\circ}$	°C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D}^{c} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 125 \text{ C}$ $V_{D} = V_{DRM(max)}; T_{j} = 125 \text{ C}$		-	0.1	0.5	mA

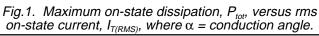
DYNAMIC CHARACTERISTICS

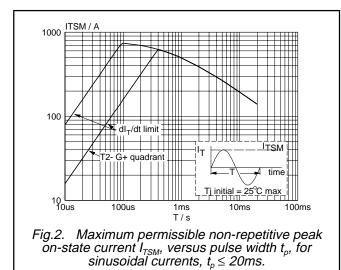
 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	-	50	-	V/µs
t _{gt}	off-state voltage Gate controlled turn-on time	exponential waveform; gate open circuit $I_{TM} = 20 \text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1 \text{ A}$; $dI_G/dt = 5 \text{ A}/\mu s$	-	2	-	μs

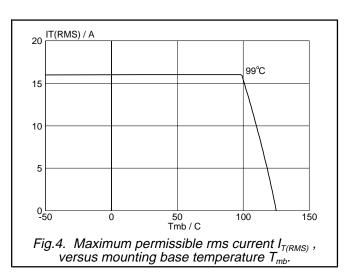
BT139 series E







 $f_{S}^{150} \xrightarrow{\text{ITSM}/\text{A}} \xrightarrow{\text{ITSM}/\text{A}}$



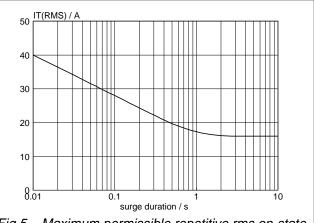
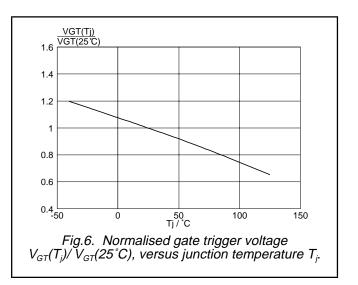
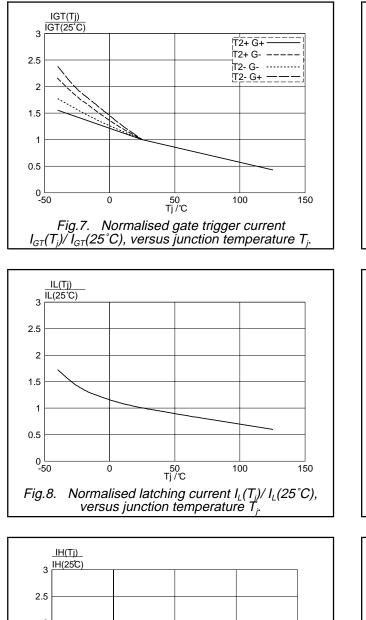
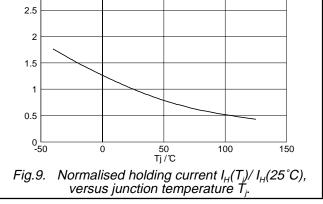


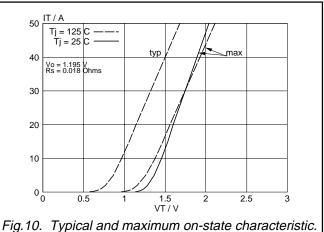
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 99^{\circ}C$.

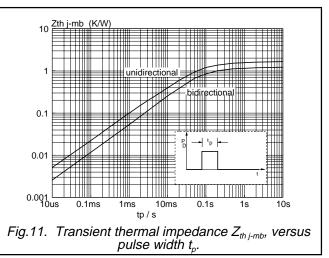


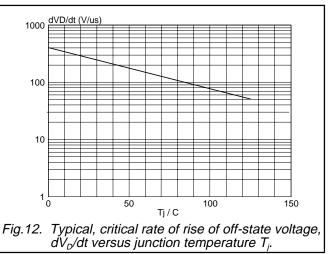
BT139 series E







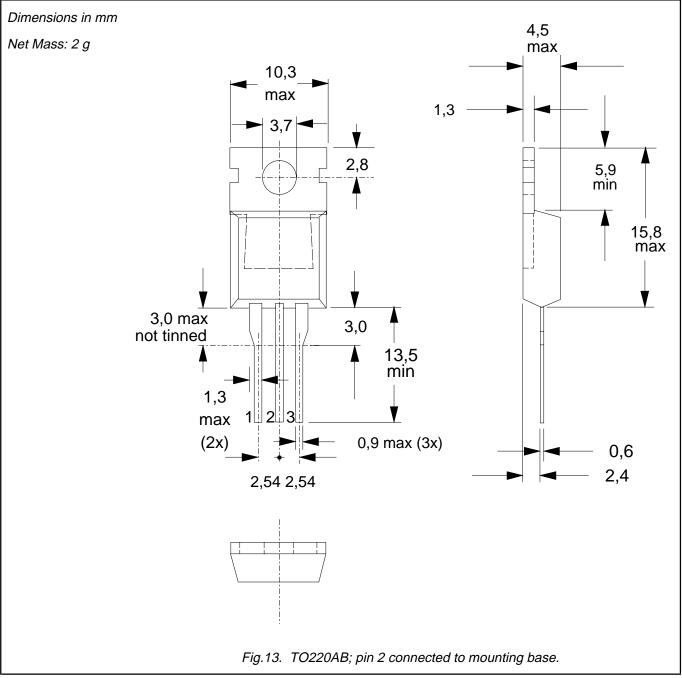




Product specification

BT139 series E

MECHANICAL DATA



Notes 1. Refer to mounting instructions for TO220 envelopes. 2. Epoxy meets UL94 V0 at 1/8".

DEFINITIONS

Data sheet status				
Objective specification	ve specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	Preliminary specification This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
© Philips Electronics N V 1997				

© Philips Electronics N.V. 1997

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.